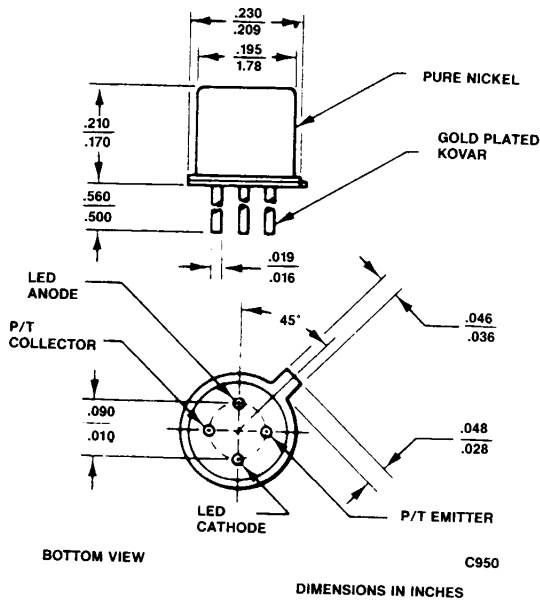


**PACKAGE DIMENSIONS**



**DESCRIPTION**

The MCT4R is a standard four-lead, TO-18 package containing a GaAs infrared emitting diode optically coupled to a silicon planar phototransistor.

**FEATURES**

- Hermetic package
- High current transfer ratio; typically 35%
- High isolation resistance, 10<sup>11</sup> ohms at 500 volts
- High voltage isolation emitter to detector
- Screened to MIL-STD-883 Class B

**APPLICATIONS**

The MCT4R is designed and manufactured to conform to the requirements of military systems. Reliability testing has proven the product capable of conforming to the screening and quality conformance requirements of MIL-STD-883C Class B devices.

<b>SCREEN—100%</b>	
<b>Characteristic</b>	<b>Method</b>
Internal Visual	2010 — Characteristics applicable to device
Stabilization Bake	1008 — 150°C. for 48 hours
Temperature Cycle	1010 — 10 cycles; -55°C., 25°C., 150°C., 25°C.
Centrifuge	2001 — Test Condition E
Hermeticity	1014 — Fine and Gross
Critical Electrical	— Data Sheet
Burn In	1015 — 160 hours @ 125°C
Final Electrical	— Data Sheet
Group A Sample Inspection	5005 Table I Subgroups
External Visual	2009

<b>LOT QUALIFICATION TESTS</b>		
<b>CHARACTERISTIC</b>	<b>METHOD</b>	<b>LTPD</b>
Subgroup I Visual Mechanical Marking Permanency Physical Dimensions	2008	15%
Subgroup II Solderability	2003	15%
Subgroup III Thermal Shock Temperature Cycle Moisture Resistance Critical Electrical	1011 — 15 cycles; 150°C. to -65°C. 1010 — 10 cycles; -55°C., 25°C., 150°C., 25°C. 1004 — Data Sheet	15%
Subgroup IV Mechanical Shock Vibration Fatigue Vibration Variable Frequency Constant Acceleration Critical Electrical	2002 — Condition B 2005 — Condition A 2007 — Condition A 2001 — Condition E — Data Sheets	15%
Subgroup V Lead Fatigue Hermeticity	2004 — Condition B <sub>2</sub> 1014 — Fine Condition A Gross Condition C	15%
Subgroup VI Salt Atmosphere	1009 — Condition A	15%

<b>LIFE TESTING 7% LTPD</b>		
<b>CHARACTERISTIC</b>	<b>METHOD</b>	<b>LTPD</b>
Subgroup VII High Temperature Storage Critical Electrical	1008 — 150°C. for 1000 hours — Data Sheet	7%
Subgroup VIII Operating Life Critical Electrical	1005 — Condition B — Data Sheets	7%
Subgroup IX Steady State Reverse Bias	1015 — Condition A; 72 hours at 150°C.	7%
Subgroup X Bond Strength	2001 — Condition C; 10 devices only	

Reference: MIL-STD-883C Test Methods and Procedures for Microelectronics.



## RELIABILITY CONDITIONED HERMETIC PHOTOTRANSISTOR OPTOCOUPLER

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.